WHAT IS CLAIMED IS:

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- 1. A capacitor anode comprising niobium powder, wherein said anode has a capacitance of at least 65,000 CV/g, and said anode is formed at a voltage of less than about 60 volts.
- 2. The capacitor anode of claim 1, wherein said anode has a capacitance of from 65,000 to about 250,000 CV/g.
 - 3. The capacitor anode of claim 1, wherein said anode has a capacitance of from about 75,000 to about 250,000 CV/g.
 - 4. The capacitor anode of claim 1, wherein said anode has a capacitance of from about 100,000 to about 250,000 CV/g.
 - 5. The capacitor anode of claim 1, wherein said anode has a capacitance of from about 125,000 to about 250,000 CV/g.
 - 6. The capacitor anode of claim 1, wherein said anode has a capacitance of from about 100,000 to about 210,000 CV/g.
 - 7. The capacitor anode of claim 1, wherein said anode is formed at a voltage of from about 30 to about 50 volts.
 - 8. The capacitor anode of claim 1, wherein said niobium powder comprises flaked niobium powder.
- 9. A capacitor anode comprising niobium powder having a BET surface area of at least about 5.5 m²/g, wherein said anode is formed at a voltage of less than about 60 volts.
 - 10. The capacitor anode of claim 9, wherein said niobium powder has a BET surface area of at least about $7.0 \text{ m}^2/\text{g}$.
 - 11. The capacitor anode of claim 9, wherein said niobium powder has a BET surface area of at least about $10 \text{ m}^2/\text{g}$.
- 12. The capacitor anode of claim 9, wherein said niobium powder has a BET surface area of from $6.0 \text{ m}^2/\text{g}$ to about $12 \text{ m}^2/\text{g}$.
 - 13. The capacitor anode of claim 1, wherein said niobium powder is sintered at a temperature of from about 1200°C to about 1750°C.

- 14. The capacitor anode of claim 1 having a phosphorus level of less than about 400 ppm.
 - 15. The capacitor anode of claim 1, wherein said niobium powder is nitrogen doped.
- 16. The capacitor anode of claim 1, wherein said niobium powder has at least about 100 ppm of nitrogen present.

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- 17. The capacitor anode of claim 1, wherein said niobium powder has nitrogen present in an amount of from about 100 ppm to about 5,000 ppm.
 - 18. The capacitor anode of claim 2, wherein said niobium powder is nitrogen doped.
 - 19. The capacitor anode of claim 3, wherein said niobium powder is nitrogen doped.
 - 20. The capacitor anode of claim 4, wherein said niobium powder is nitrogen doped.
 - 21. The capacitor anode of claim 5, wherein said niobium powder is nitrogen doped.
 - 22. The capacitor anode of claim 6, wherein said niobium powder is nitrogen doped.
 - 23. The capacitor anode of claim 7, wherein said niobium powder is nitrogen doped.
 - 24. The capacitor anode of claim 8, wherein said niobium powder is nitrogen doped.
 - 25. The capacitor anode of claim 9, wherein said niobium powder is nitrogen doped.
 - 26. The capacitor anode of claim 10, wherein said niobium powder is nitrogen doped.
- 27. The capacitor anode of claim 2, wherein said niobium powder has at least about 100 ppm of nitrogen present.
- 28. The capacitor anode of claim 3, wherein said niobium powder has at least about 100 ppm of nitrogen present.
 - 29. The capacitor anode of claim 4, wherein said niobium powder has at least about 100 ppm of nitrogen present.
 - 30. The capacitor anode of claim 5, wherein said niobium powder has at least about 100 ppm of nitrogen present.
 - 31. The capacitor anode of claim 6, wherein said niobium powder has at least about 100 ppm of nitrogen present.
 - 32. The capacitor anode of claim 7, wherein said niobium powder has at least about 100 ppm of nitrogen present.
- 33. The capacitor anode of claim 8, wherein said niobium powder has at least about 100 ppm of nitrogen present.

- 34. The capacitor anode of claim 9, wherein said niobium powder has at least about 100 ppm of nitrogen present.
- 35. The capacitor anode of claim 10, wherein said niobium powder has at least about 100 ppm of nitrogen present.